## Sensitive gate SCRs, 1A

## Main Features

| Symbol | Value | Unit |
| :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{T}(\mathrm{RMS})}$ | 1 | A |
| $\mathrm{~V}_{\mathrm{DRM}} / \mathrm{V}_{\text {RRM }}$ | 600 to 800 | V |
| $\mathrm{I}_{\mathrm{GT}}$ | 10 to 200 | $\mu \mathrm{~A}$ |

## DESCRIPTION

Thanks to highly sensitive triggering levels, the 1PT gate current is limited, such as capacitive discharge ignitions, motor control in kitchen aids, overvoltage crowbar protection in low power supplies among others. Available in through-hole or surface-mount packages, they provide an optimized performance in a limited space area.

The 1PT SCR series provide high dV/dt rate with strong resistance to electromagnetic interface. They are especially recommended for use on residual current circuit breaker, straight hair dryer and igniter etc.


| ABSOLUTE MAXIMUM RATINGS |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| PARAMETER | SYMBOL | TEST CONDITIONS |  | VALUE | UNIT |
| RMS on-state current full sine wave ( $180^{\circ}$ conduction angle ) | $\mathrm{I}_{\text {(RMS }}$ | TO-92 | $\mathrm{T}_{\mathrm{C}}=50^{\circ} \mathrm{C}$ | 1 | A |
|  |  | SOT-89 | $\mathrm{T}_{\mathrm{C}}=60^{\circ} \mathrm{C}$ |  |  |
|  |  | SOT-223 | $\mathrm{T}_{\mathrm{C}}=75^{\circ} \mathrm{C}$ |  |  |
| Average on-state current ( $180^{\circ}$ conduction angle) | $\mathrm{I}_{\text {( }(\mathrm{AV})}$ | TO-92 | $\mathrm{T}_{\mathrm{C}}=50^{\circ} \mathrm{C}$ | 0.6 | A |
|  |  | SOT-89 | $\mathrm{T}_{\mathrm{C}}=60^{\circ} \mathrm{C}$ |  |  |
|  |  | SOT-223 | $\mathrm{T}_{\mathrm{C}}=75^{\circ} \mathrm{C}$ |  |  |
| Non repetitive surge peak on-state current (full cycle, $\mathrm{T}_{\mathrm{j}}$ initial $=25^{\circ} \mathrm{C}$ ) | $I_{\text {TSM }}$ | $\mathrm{F}=50 \mathrm{~Hz}$ | $\mathrm{T}=20 \mathrm{~ms}$ | 12 | A |
|  |  | $\mathrm{F}=60 \mathrm{~Hz}$ | $\mathrm{T}=16.7 \mathrm{~ms}$ | 12.6 |  |
| $1^{2} t$ Value for fusing | $1^{2} \mathrm{t}$ | $\mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}$ |  | 0.72 | $\mathrm{A}^{2} \mathrm{~s}$ |
| Critical rate of rise of on-state current $\mathrm{I}_{\mathrm{G}}=2 \mathrm{XI}_{\mathrm{GT}}, \mathrm{t}_{\mathrm{r}} \leq 100 \mathrm{~ns}$ | dl/dt | $\mathrm{F}=60 \mathrm{~Hz}$ | $\mathrm{T}_{J}=110^{\circ} \mathrm{C}$ | 50 | A/ $/ \mathrm{s}$ |
| Peak gate current | $\mathrm{I}_{\mathrm{GM}}$ | $\mathrm{T}_{\mathrm{p}}=20 \mu \mathrm{~s}$ | $\mathrm{T}_{\mathrm{J}}=110^{\circ} \mathrm{C}$ | 0.3 | A |
| Forward peak gate power | $\mathrm{P}_{\mathrm{GM}}$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, Pulse width $\leq 0.1 \mu \mathrm{~s}$ |  | 0.5 | W |
| Average gate power dissipation | $\mathrm{P}_{\mathrm{G}(\mathrm{AV})}$ | $\mathrm{T}_{J}=110^{\circ} \mathrm{C}$ |  | 0.1 | w |
| Repetitive peak off-state voltage | $\mathrm{V}_{\text {DRM }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | 600 and 800 | V |
| Repetitive peak reverse voltage | $\mathrm{V}_{\text {RRM }}$ |  |  |  |  |
| Storage temperature range | $\mathrm{T}_{\text {stg }}$ |  |  | -40 to +150 |  |
| Operating junction temperature range | $\mathrm{T}_{\mathrm{j}}$ |  |  | - 40 to +110 | ${ }^{\circ} \mathrm{C}$ |

## 1PT Series

| ELECTRICAL SPECIFICATIONS ( $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ unless otherwise specified) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| SYMBOL | TEST CONDITIONS |  |  | 1PTxxxx | Unit |
| $I_{\text {GT }}$ | $\mathrm{V}_{\mathrm{D}}=12 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ |  | Min. | 10 | $\mu \mathrm{A}$ |
|  |  |  | Max. | 200 |  |
| $V_{G T}$ |  |  | Max. | 0.8 | V |
| $V_{G D}$ | $\begin{aligned} & V_{D}=V_{D R M}, R_{L}=3.3 \mathrm{~K} \Omega \\ & R_{G K}=1 \mathrm{~K} \Omega, T_{j}=110^{\circ} \mathrm{C} \end{aligned}$ |  | Min. | 0.2 | V |
| $\mathrm{I}_{\mathrm{H}}$ | $\mathrm{I}_{\mathrm{T}}=50 \mathrm{~mA}, \mathrm{R}_{\mathrm{GK}}=1 \mathrm{~K} \Omega$ |  | Max. | 5 | mA |
| IL | $\mathrm{I}_{\mathrm{G}}=1 \mathrm{~mA}, \mathrm{R}_{\mathrm{GK}}=1 \mathrm{~K} \Omega$ |  | Max. | 6 | mA |
| dV/dt | $\mathrm{V}_{\mathrm{D}}=67 \% \mathrm{~V}_{\mathrm{DRM}}, \mathrm{R}_{\mathrm{GK}}=1 \mathrm{~K} \Omega, \mathrm{~T}_{\mathrm{j}}=110^{\circ} \mathrm{C}$ |  | TYP. | 200 | V/ $/ \mathrm{s}$ |
| $\mathrm{V}_{\text {TM }}$ | $\mathrm{I}_{\mathrm{T}}=2.0 \mathrm{~A}, \mathrm{t}_{\mathrm{P}}=380 \mu \mathrm{~s}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | Max. | 1.7 | V |
| IDRM | $\mathrm{V}_{\mathrm{D}}=\mathrm{V}_{\mathrm{DRM}}, \mathrm{V}_{\mathrm{R}}=\mathrm{V}_{\text {RRM }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | Max. | 5 | $\mu \mathrm{A}$ |
| $I_{\text {RRM }}$ | $\mathrm{R}_{\mathrm{GK}}=220 \Omega$ | $\mathrm{T}_{\mathrm{J}}=110^{\circ} \mathrm{C}$ | Max. | 0.1 | mA |
| $\mathrm{V}_{\text {to }}$ | Threshold voltage | $\mathrm{T}_{\mathrm{J}}=110^{\circ} \mathrm{C}$ | Max. | 0.85 | V |
| $\mathrm{R}_{\mathrm{d}}$ | Dynamic resistance | $\mathrm{T}_{\mathrm{J}}=110^{\circ} \mathrm{C}$ | Max. | 60 | $\mathrm{M} \Omega$ |

THERMAL RESISTANCE

| SYMBOL | Parameter |  | VALUE | UNIT |
| :---: | :---: | :--- | :--- | :---: |
| $\mathrm{R}_{\text {th(i-c) }}$ | Junction to case (AC) | TO-92 | 70 |  |
|  |  |  | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |  |
|  |  | SOT-223 | 38 |  |
|  |  |  |  |  |

## PRODUCT SELECTOR

| PART NUMBER | VOLTAGE ( $\mathbf{x x}$ ) |  | SENSITIVITY | PACKAGE |
| :---: | :---: | :---: | :---: | :---: |
|  | 600 V | 800 V |  | TO-92 |
| 1PTxxE-03 | V | V | $10 \sim 30 \mu \mathrm{~A}$ | TO-92 |
| 1PTxxE-05 | V | V | $20 \sim 50 \mu \mathrm{~A}$ | TO-92 |
| 1PTxxE-06 | V | V | $30 \sim 60 \mu \mathrm{~A}$ | TO-92 |
| 1PTxxE-08 | V | V | $50 \sim 80 \mu \mathrm{~A}$ | TO-92 |
| 1PTxxE-S | V | V | $70 \sim 200 \mu \mathrm{~A}$ | TO-92 |
| 1PTxxE | V | V | $10 \sim 200 \mu \mathrm{~A}$ | SOT-223 |
| 1PTxxS | V | V | $10 \sim 200 \mu \mathrm{~A}$ | SOT-89 |
| 1PTxxN | V | $10 \sim 200 \mu \mathrm{~A}$ |  |  |


| ORDERING INFORMATION |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ORDERING TYPE | MARKING | PACKAGE | WEIGHT | BASE Q'TY | DELIVERY MODE |  |
| 1PTxxE-yy | 1PTxxE-yy | TO-92 | 0.23 g | 500 | Bag |  |
| 1PTxxS | 1PTxxS | SOT-223 | 0.24 g | 4000 | 7"T\&R |  |
| 1PTxxN | 1PTxxN | SOT-89 | 0.2 g | 4000 | 7"T\&R |  |

Note: $x x=$ voltage, $y y=$ sensitivity

## ORDERING INFORMATION SCHEME

## 1 PT 06 E - S

Current
1 = 1A, IT(RMS)
SCR series

Voltage Code
$06=600 \mathrm{~V}$
$08=800 \mathrm{~V}$
Package type
$\mathrm{E}=\mathrm{TO}-92$
N = SOT-89
$S=S O T-223$
IGT Sensitivity
$03=10 \sim 30 \mu \mathrm{~A}$
$05=20 \sim 50 \mu \mathrm{~A}$
$06=30 \sim 60 \mu \mathrm{~A}$
$08=50 \sim 80 \mu \mathrm{~A}$
$\mathrm{~S}=70 \sim 200 \mu \mathrm{~A}$
Blank $=10 \sim 200 \mu \mathrm{~A}$

Fig. 1 Maximum power dissipation versus RMS on-state current


Fig. 3 On-state characteristics (maximum values)


Fig. 2 RMS on-state current versus case temperature (full cycle)


Fig. 4 Surge peak on-state current versus number of cycles


## 1PT Series

Fig. 5 Non-repetitive surge peak on-state current for a sinusoidal pulse with width $\mathrm{tp}<10 \mathrm{~ms}$, and corresponding value of $\mathrm{I}^{2} \mathrm{t}$


Fig. 6 Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)


## Case Style



## Case Style

## SOT-223



All dimensions in millimeters(inches)

## 3(G) $-\frac{2(\mathrm{~A})}{1}$

SOT-89


All dimensions in millimeters(inches)

